

UTT15P06

Power MOSFET

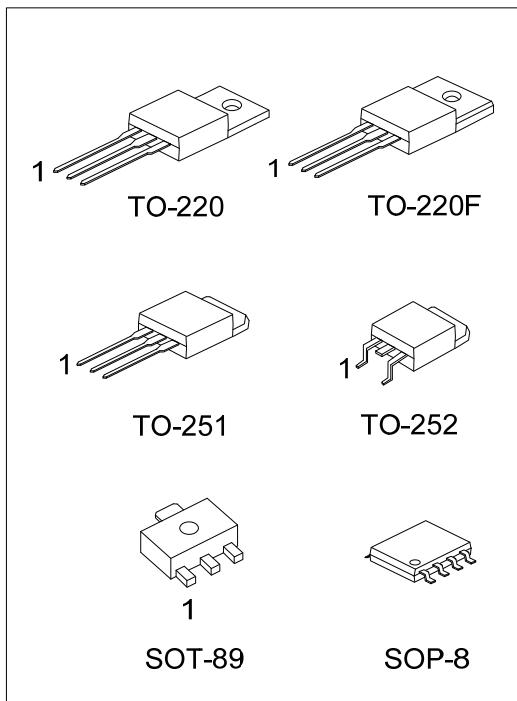
**-15A, -60V P-CHANNEL
POWER MOSFET**

■ DESCRIPTION

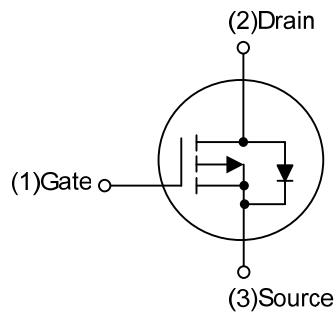
The UTC **UTT15P06** is a P-channel power MOSFET using UTC's advanced technology to provide the customers with high switching speed, cost-effectiveness and minimum on-state resistance. It can also withstand high energy in the avalanche.

■ FEATURES

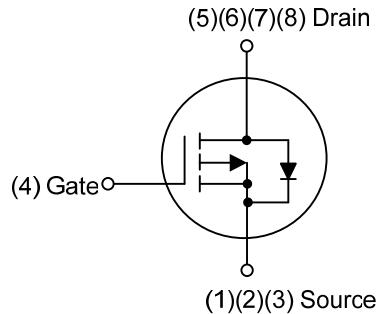
- * $R_{DS(ON)} \leq 75 \text{ m}\Omega$ @ $V_{GS}=-10\text{V}$, $I_D=-15\text{A}$
- * $R_{DS(ON)} \leq 120 \text{ m}\Omega$ @ $V_{GS}=-4.5\text{V}$, $I_D=-7.5\text{A}$
- * High Switching Speed



■ SYMBOL



SOT-89/TO-220/TO-220F
TO-251/TO-252

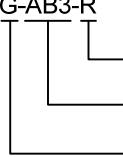


SOP-8

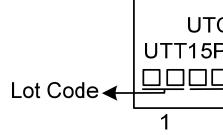
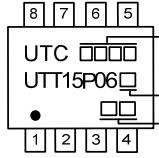
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment								Packing
Lead Free	Halogen Free		1	2	3	4	5	6	7	8	
UTT15P06L-AB3-R	UTT15P06G-AB3-R	SOT-89	G	D	S	-	-	-	-	-	Tube
UTT15P06L-TA3-T	UTT15P06G-TA3-T	TO-220	G	D	S	-	-	-	-	-	Tube
UTT15P06L-TF3-T	UTT15P06G-TF3-T	TO-220F	G	D	S	-	-	-	-	-	Tube
UTT15P06L-TM3-T	UTT15P06G-TM3-T	TO-251	G	D	S	-	-	-	-	-	Tube
UTT15P06L-TN3-R	UTT15P06G-TN3-R	TO-252	G	D	S	-	-	-	-	-	Tape Reel
UTT15P06L-S08-R	UTT15P06G-S08-R	SOP-8	S	S	S	G	D	D	D	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

 (1)Packing Type (2)Package Type (3)Green Package	(1) T: Tube, R: Tape Reel (2) AB3: SOT-89, TA3: TO-220, TF3: TO-220F, TM3: TO-251, TN3: TO-252, S08: SOP-8 (3) G: Halogen Free and Lead Free, L: Lead Free
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■ MARKING

PACKAGE	MARKING
SOT-89	
TO-220 / TO-220F TO-251 / TO-252	
SOP-8	

■ ABSOLUTE MAXIMUM RATINGS ($T_c=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	-60	V
Gate-Source Voltage		V_{GSS}	± 25	V
Drain Current	Continuous	I_D	-15	A
	Pulsed	I_{DM}	-30	A
Avalanche Energy	Single Pulsed (Note 3)	E_{AS}	16.2	mJ
Power Dissipation	SOT-89	P_D	4.3	W
	TO-220		79	W
	TO-220F		37	W
	TO-251/TO-252		39	W
	SOP-8		3	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. $L = 0.1\text{mH}$, $I_{AS} = -18\text{A}$, $V_{DD} = -30\text{V}$, $R_G = 25 \Omega$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient (Steady state)	SOT-89	θ_{JA}	180	$^\circ\text{C/W}$
	TO-220/TO-220F		62	$^\circ\text{C/W}$
	TO-251/TO-252		110	$^\circ\text{C/W}$
	SOT-8		125	$^\circ\text{C/W}$
Junction to Case	SOT-89	θ_{JC}	29	$^\circ\text{C/W}$
	TO-220		1.58	$^\circ\text{C/W}$
	TO-220F		3.3	$^\circ\text{C/W}$
	TO-251/TO-252		3.2 (Note)	$^\circ\text{C/W}$
	SOT-8		41.67	$^\circ\text{C/W}$

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

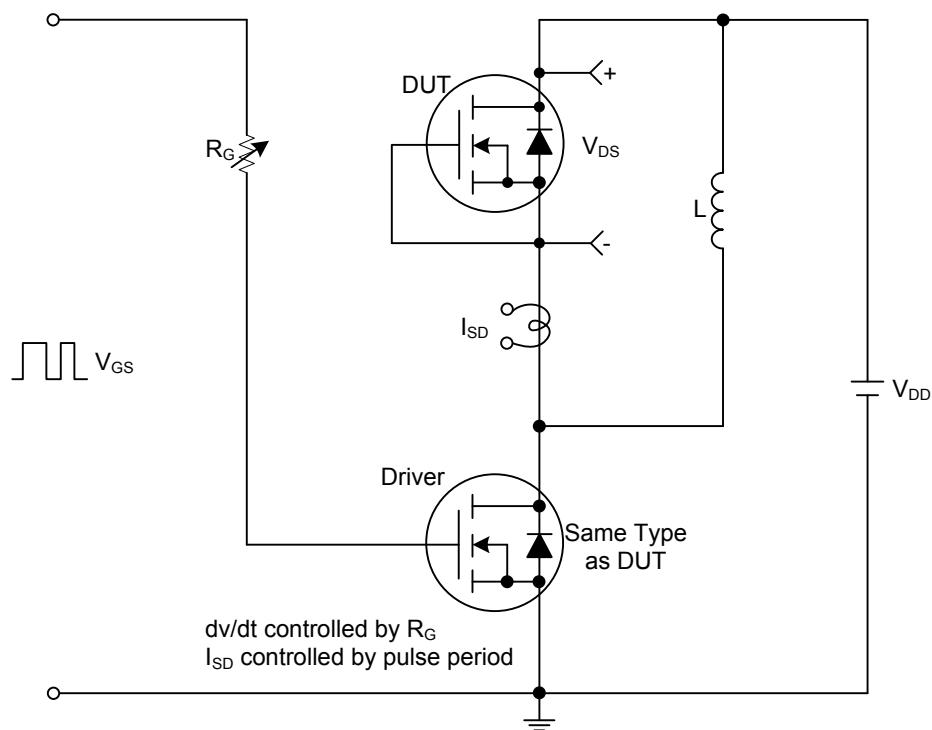
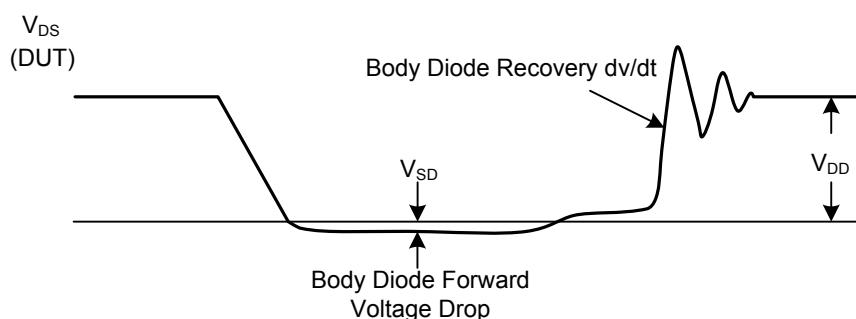
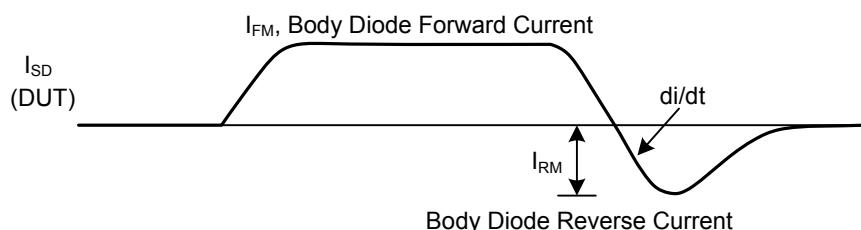
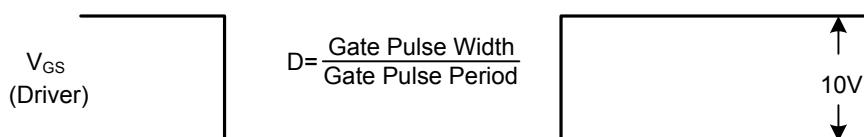
■ ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D=-250\mu\text{A}, V_{GS}=0\text{V}$	-60			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=-60\text{V}, V_{GS}=0\text{V}$			-1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=+25\text{V}, V_{DS}=0\text{V}$			+100	nA
		$V_{GS}=-25\text{V}, V_{DS}=0\text{V}$			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{DS}=V_{GS}, I_D=-250\mu\text{A}$	-1.0		-3.0	V
Static Drain-Source On-State Resistance	$R_{DS(\text{ON})}$	$V_{GS}=-10\text{V}, I_D=-15\text{A}$			75	$\text{m}\Omega$
		$V_{GS}=-4.5\text{V}, I_D=-7.5\text{A}$			120	$\text{m}\Omega$
DYNAMIC PARAMETERS (Note 2)						
Input Capacitance	C_{ISS}	$V_{GS}=0\text{V}, V_{DS}=-25\text{V}, f=1.0\text{MHz}$		1086		pF
Output Capacitance	C_{OSS}			97		pF
Reverse Transfer Capacitance	C_{RSS}			61.6		pF
SWITCHING PARAMETERS						
Total Gate Charge	Q_G	$V_{DS}=-30\text{V}, V_{GS}=-10\text{V}, I_D=-15\text{A}$ $I_G=-1\text{mA}$ (Note 1, 2)		22		nC
Gate to Source Charge	Q_{GS}			5		nC
Gate to Drain Charge	Q_{GD}			3		nC
Turn-ON Delay Time	$t_{D(\text{ON})}$			6		ns
Rise Time	t_R			16		ns
Turn-OFF Delay Time	$t_{D(\text{OFF})}$			30		ns
Fall-Time	t_F			20		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_C=25^\circ\text{C}$) (Note 2)						
Maximum Body-Diode Continuous Current	I_S				-15	A
Maximum Body-Diode Pulsed Current	I_{SM}				-30	A
Drain-Source Diode Forward Voltage	V_{SD}	$I_F=-15\text{A}, V_{GS}=0\text{V}$ (Note 1)		-1.0	-1.5	V
Body Diode Reverse Recovery Time	t_{rr}	$I_S=-15\text{A}, V_{GS}=0\text{V},$ $dI_F/dt=100\text{A}/\mu\text{s}$ (Note 2)		40		ns
Body Diode Reverse Recovery Charge	Q_{rr}			35		nC

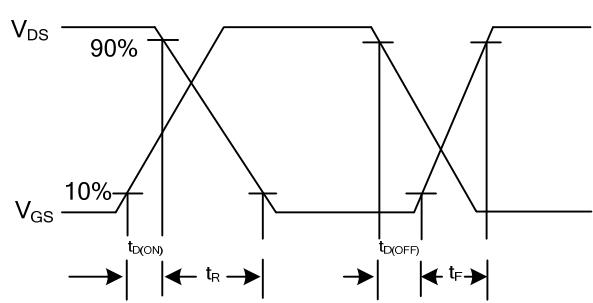
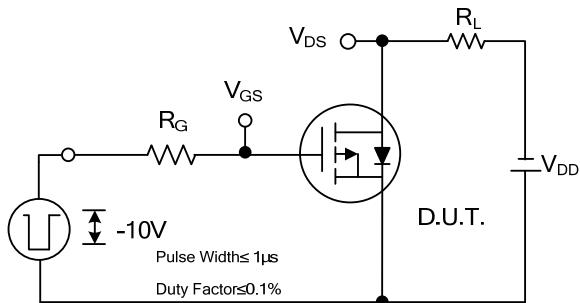
Notes: 1. Pulse Test : Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$.

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

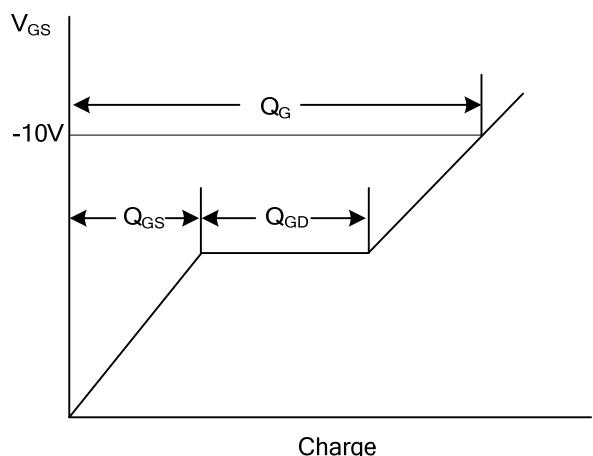
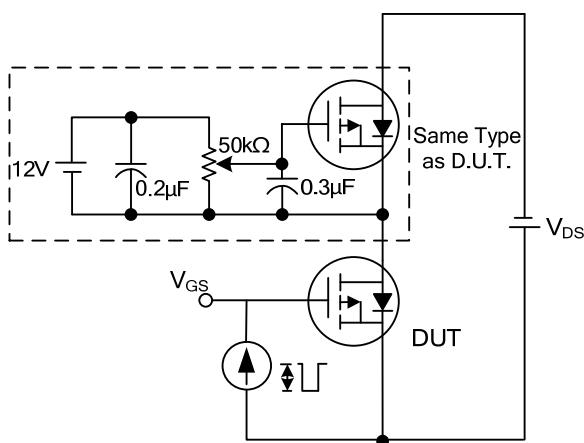
Peak Diode Recovery dV/dt Test CircuitPeak Diode Recovery dV/dt Test Circuit and WaveformsPeak Diode Recovery dV/dt Waveforms

■ TEST CIRCUITS AND WAVEFORMS



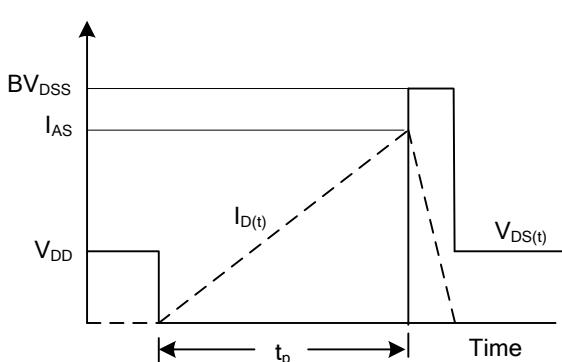
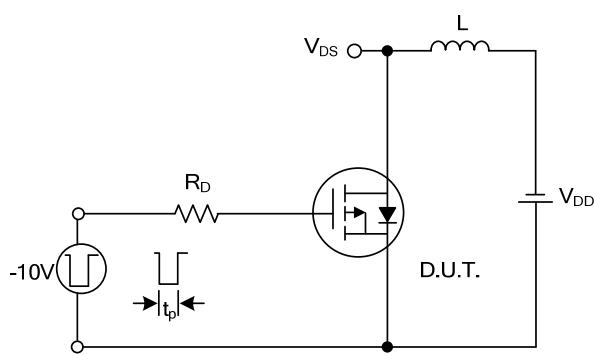
Switching Test Circuit

Switching Waveforms



Gate Charge Test Circuit

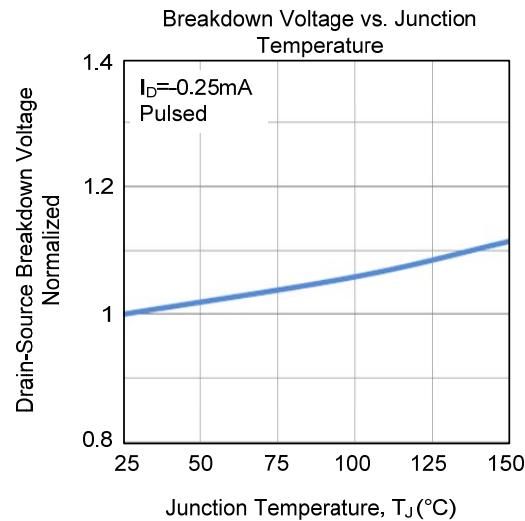
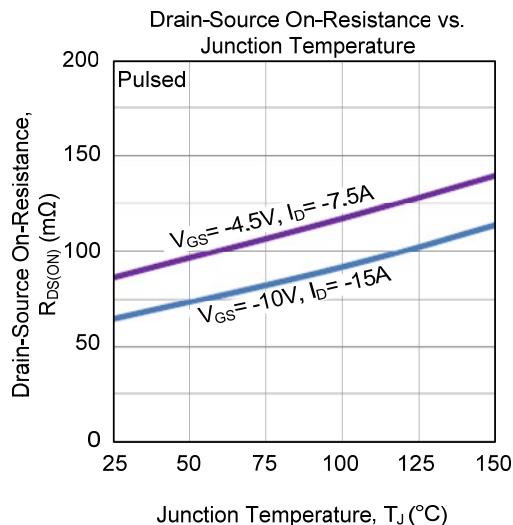
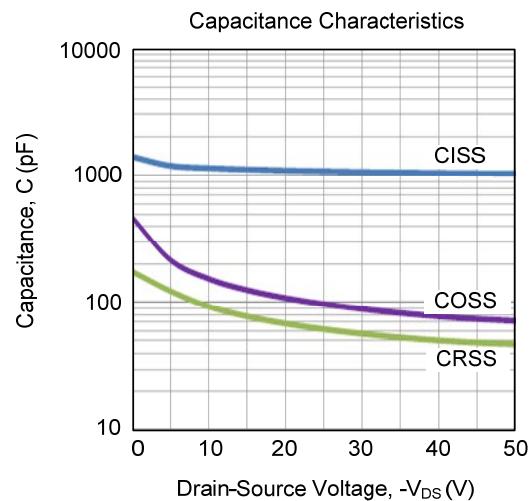
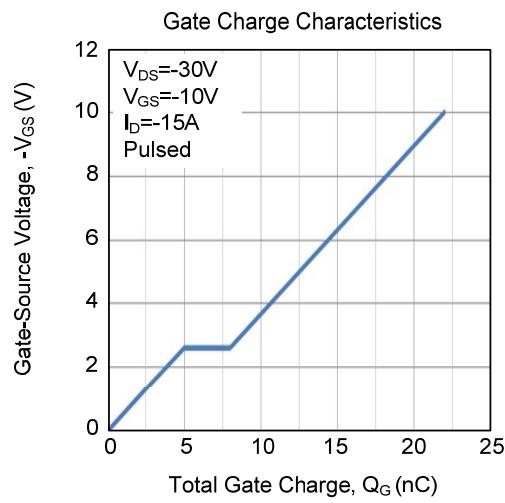
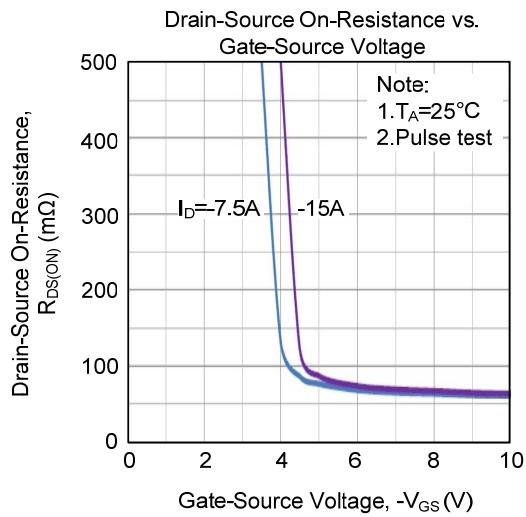
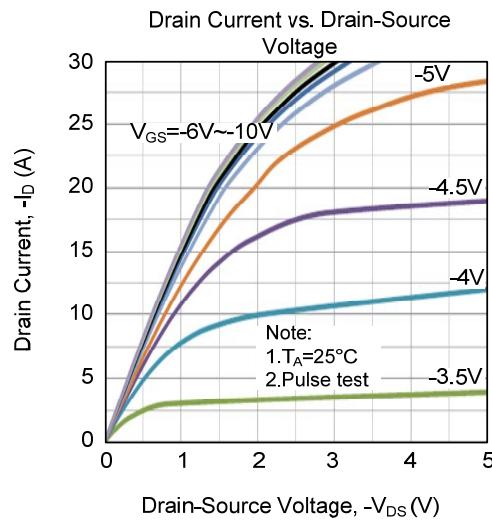
Gate Charge Waveform



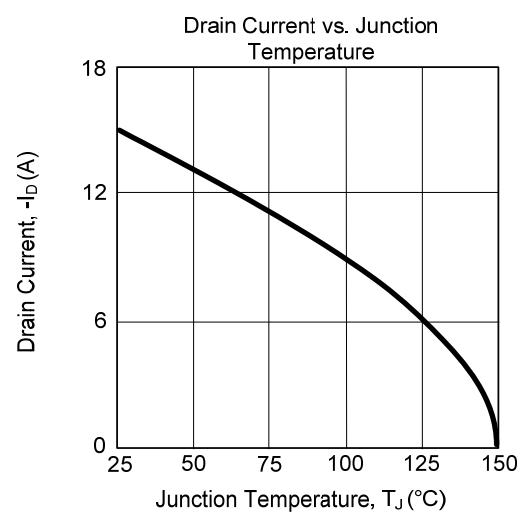
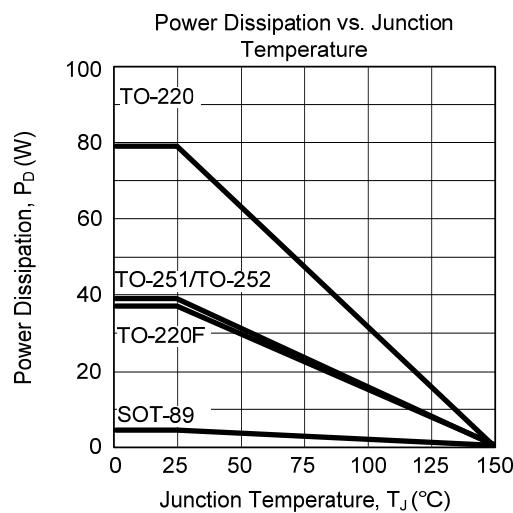
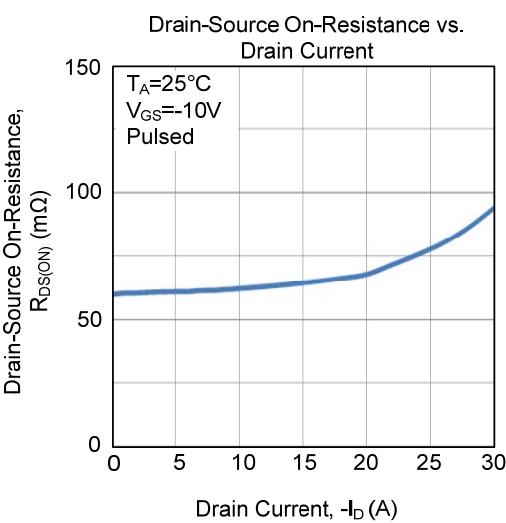
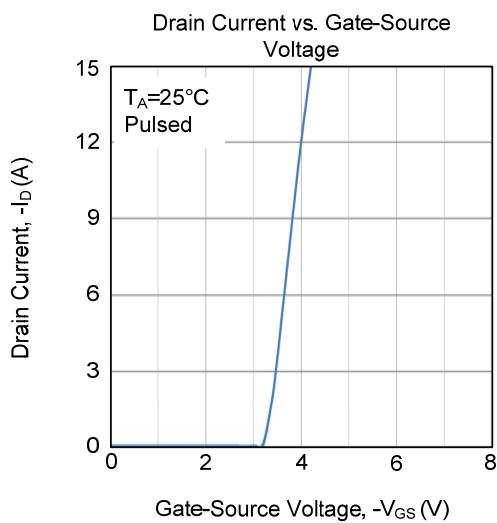
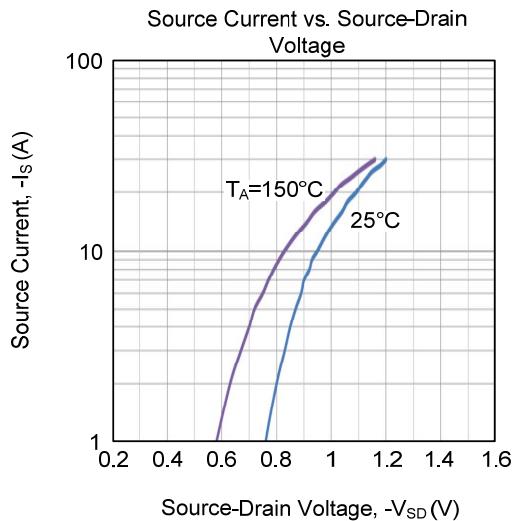
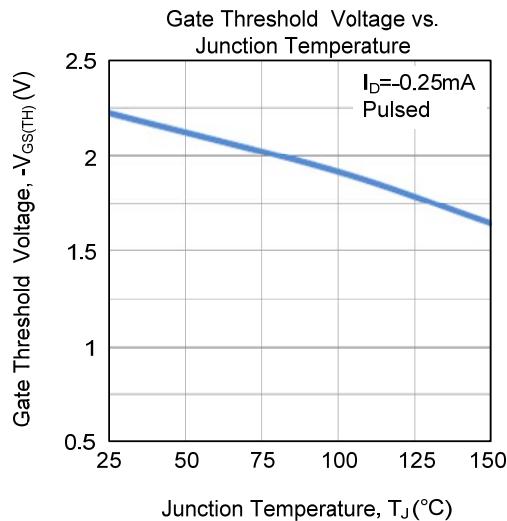
Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

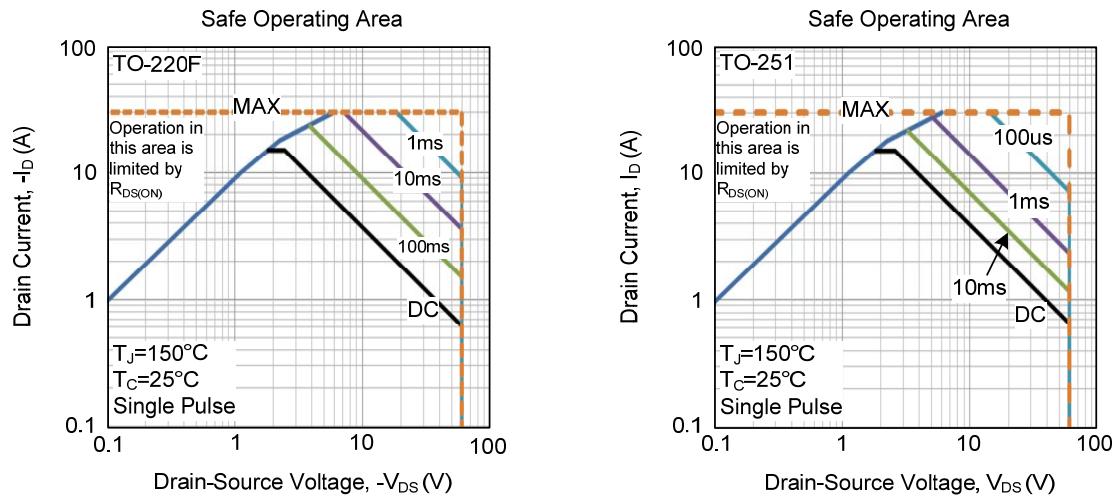
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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